EMB10 / UMB10N / IMB10A

PNP -100mA -50V Complex Digital Transistors (Bias Resistor Built-in Transistors) Datasheet

Parameter	Tr1 and Tr2
V _{CC}	-50V
I _{C(MAX.)}	-100mA
R ₁	2.2 k Ω
R_2	47kΩ

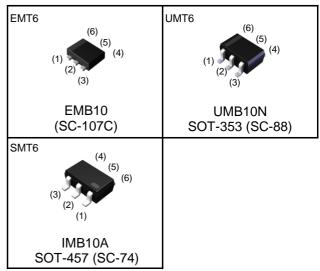
Features

- 1) Built-In Biasing Resistors.
- 2) Two DTA123J chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

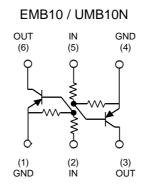
Application

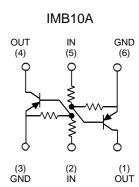
Inverter circuit, Interface circuit, Driver circuit

Outline



●Inner circuit





Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMB10	EMT6	1616	T2R	180	8	8,000	B10
UMB10N	UMT6	2021	TR	180	8	3,000	B10
IMB10A	SMT6	2928	T108	180	8	3,000	B10

● **Absolute maximum ratings** (Ta = 25°C)

<For Tr1 and Tr2 in common>

Para	ameter	Symbol	Values	Unit
Supply voltage		V _{cc}	–50	V
Input voltage		V _{IN}	−12 to +5	V
Output current		Io	-100	mA
Collector current		I _{C(MAX.)} *1	-100	mA
Power dissipation	Power dissipation EMB10 / UMB10N		150 (Total) ^{*3}	mW
IMB10A		P _D *2	300 (Total)*4	mW
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

●Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100\mu A$	-	ı	-0.5	V
input voitage	$V_{I(on)}$	$V_0 = -0.3V, I_0 = -5mA$	-1.1	-	-	V
Output voltage	$V_{O(on)}$	$I_0 / I_1 = -5 \text{mA} / -0.25 \text{mA}$	-	-0.1	-0.3	V
Input current	I ₁	$V_1 = -5V$	-	-	-3.6	mA
Output current	I _{O(off)}	$V_{CC} = -50V, V_1 = 0V$	-	-	-0.5	μΑ
DC current gain	Gı	$V_0 = -5V, I_0 = -10mA$	80	-	-	-
Input resistance	R ₁	-	1.54	2.2	2.86	kΩ
Resistance ratio	R ₂ /R ₁	-	17	21	26	-
Transition frequency	f _T *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz	-	250	-	MHz

^{*1} Characteristics of built-in transistor

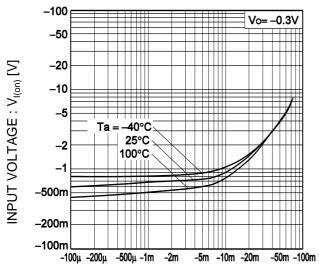
^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

^{*4 200}mW per element must not be exceeded.

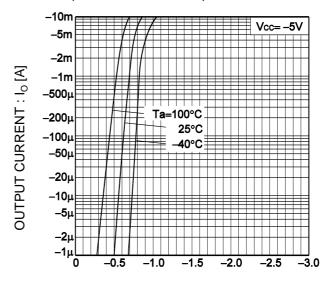
●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics)



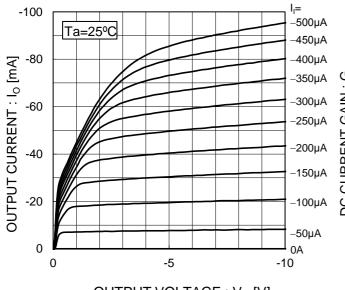
OUTPUT CURRENT : Io [A]

Fig.2 Output current vs. input voltage (OFF characteristics)



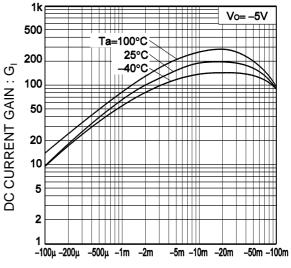
INPUT VOLTAGE : $V_{I(off)}[V]$

Fig.3 Output current vs. output voltage



OUTPUT VOLTAGE: Vo [V]

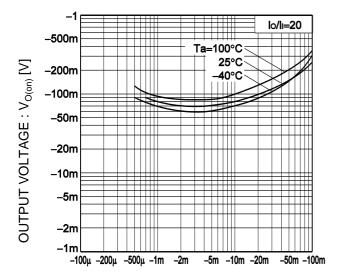
Fig.4 DC current gain vs. output current



OUTPUT CURRENT : Io [A]

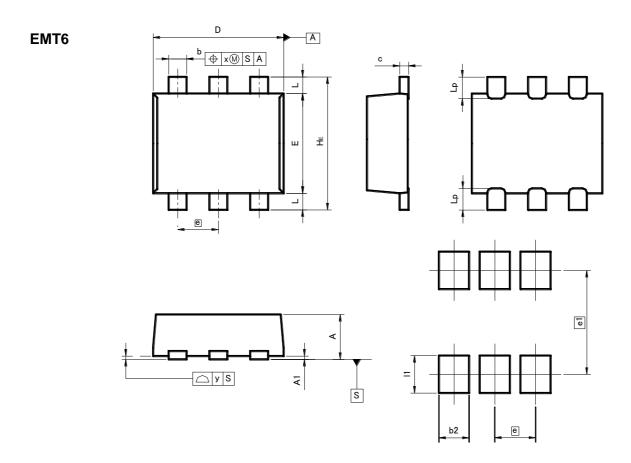
●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



OUTPUT CURRENT : I_O [A]

●Dimensions (Unit : mm)



Patterm of terminal position areas

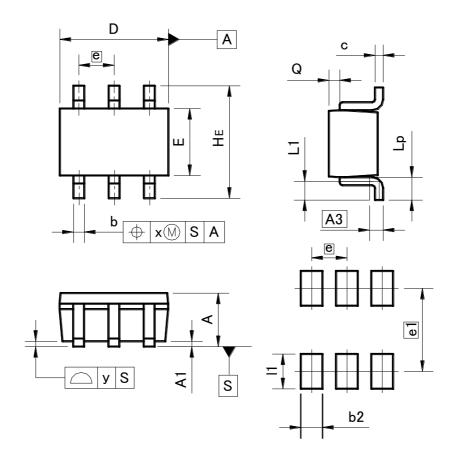
DIM	MILIMETERS		INC	HES
DIIVI	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
Α	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
е	0.9	50	0.02	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	_	0.35	-	0.014
х	_	0.10	_	0.004
V	_	0.10	_	0.004

DIM	MILIMETERS		INCHES	
DIN	MIN MAX		MIN	MAX
e1	1.25		0.049	
b2	_	0.37	ı	0.015
l1	_	0.45	_	0.018

Dimension in mm/inches

●Dimensions (Unit : mm)

UMT6



Patterm of terminal position areas

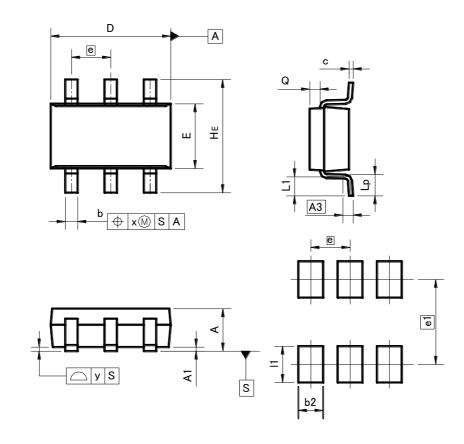
DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	ı	0.039
A1	0.00	0.10	0	0.004
A3	0.2	25	0.0	01
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.65		0.03	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
х	-	0.10	_	0.004
У	-	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	1.55		0.06		
b2	-	0.40	_	0.016	
11	1	0.65	ı	0.026	

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT6



Patterm of terminal position areas

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0	0.004
A3	0.2	25	0.0	01
b	0.25	0.40	0.01	0.016
С	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
E	1.50	1.80	0.059	0.071
е	0.0	95	0.04	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х	_	0.20	-	0.008
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN MAX		MIN	MAX	
e1	2.10		0.08		
b2		0.60	ı	0.024	
11	_	0.90	-	0.035	

Dimension in mm/inches

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